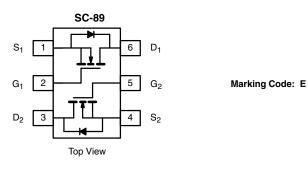




N-Channel 60 V (D-S) MOSFET

PRODUCT	DUCT SUMMARY				
V _{DS(min)} (V)	$R_{DS(on)}\left(\Omega\right)$	V _{GS(th)} (V)	I _D (mA)		
60	1.40 at V _{GS} = 10 V	1 to 2.5	500		



Ordering Information: Si1026X-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Low On-Resistance: 1.40 Ω
 Low Threshold: 2 V (typ.)
 Low Input Capacitance: 30 pF
- Fast Switching Speed: 15 ns (typ.)
- Low Input and Output Leakage
- ESD Protected: 2000 V
- Miniature Package
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- Low Offset Voltage
- Low-Voltage Operation
- High-Speed Circuits
- · Low Error Voltage
- Small Board Area

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	60		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Dusin Comment /T 450 0008	T _A = 25 °C	I	305		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		230	220	
Pulsed Drain Current ^b		I _{DM}	- 650		mA
Continuous Source Current (Diode Conduction) ^a		I _S	450	380	
M	T _A = 25 °C	P _D	280	250	mW
Maximum Power Dissipation ^a	T _A = 85 °C		145	130	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V

Notes:

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

ROHS COMPLIANT HALOGEN FREE

Vishay Siliconix



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min. Typ.		Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 10 \mu\text{A}$	60			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 0.25 \text{ mA}$	1		2.5		
Cata Bady Laglaga	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 150	nA	
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 50		
Zara Cata Valtaga Prain Current	1	V _{DS} = 60 V, V _{GS} = 0 V			1	μА	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			10		
On Otata Daria Onemania	1	V _{DS} = 10 V, V _{GS} = 4.5 V	500			mA	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 7.5 V, V _{GS} = 10 V	800				
Drain-Source On-Resistance ^a		$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			3.0		
	R _{DS(on)}	V _{GS} = 10 V, I _D = 500 mA			1.40	Ω	
		$V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}, T_J = 125 \text{ °C}$			2.50		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 200 mA		200		mS	
Diode Forward Voltage ^a	V_{SD}	$V_{GS} = 0 \text{ V, } I_{S} = 200 \text{ mA}$			1.40	V	
Dynamic ^b							
Total Gate Charge	Qg			600			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, I_D = 250 \text{ mA}, V_{GS} = 4.5 \text{ V}$		120		рС	
Gate-Drain Charge	Q_{gd}			225			
Input Capacitance	C _{iss}	.,		30			
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz		6		pF	
Reverse Transfer Capacitance	C _{rss}	1 – 1 WILIZ		3]	
Switching ^{b, c}			•	•			
Turn-On Time	t _(on)	V_{DD} = 30 V, R_L = 150 Ω		15			
Turn-Off Time	t _(off)	I_D = 200 mA, V_{GEN} = 10 V, R_g = 10 Ω		20		ns	

Notes:

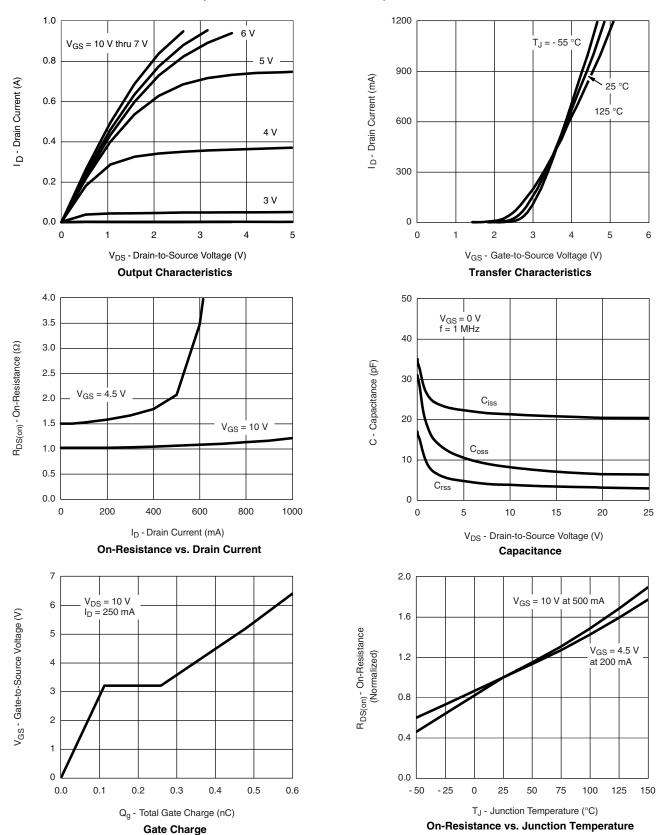
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





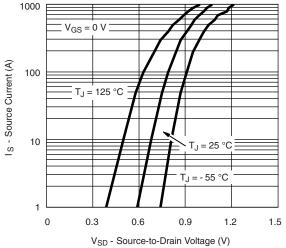
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

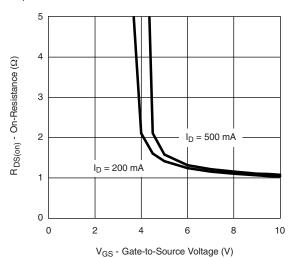


Vishay Siliconix

VISHAY

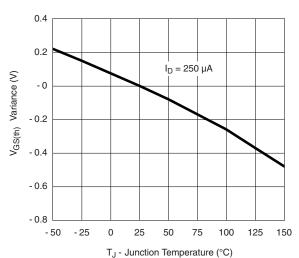
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



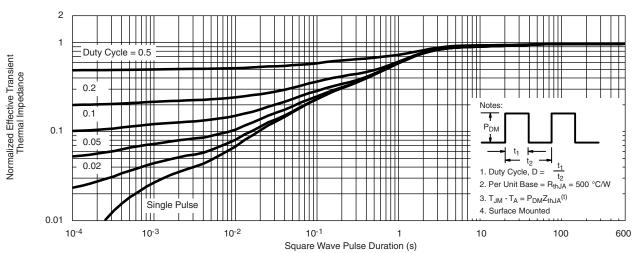


Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage Variance Over Temperature

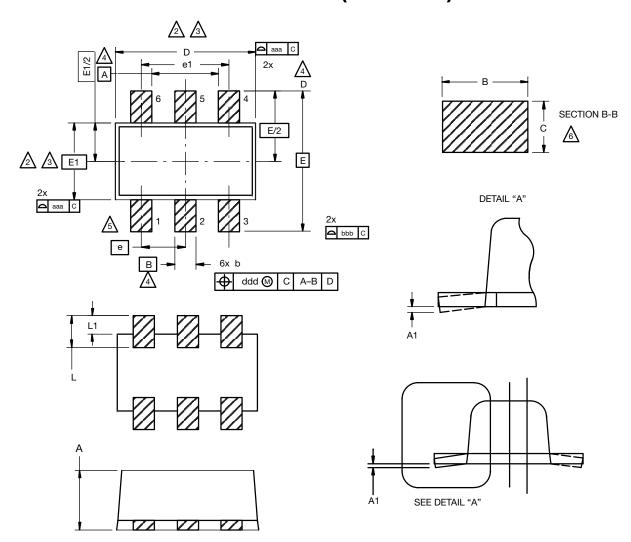


Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71434.



SC-89 6-Leads (SOT-563F)



Notes

1. Dimensions in millimeters.

Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.

Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

ADatums A, B and D to be determined 0.10 mm from the lead tip.

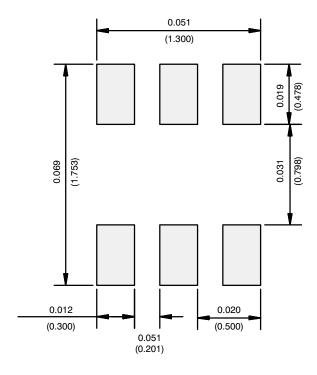
A Terminal numbers are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIM.		MILLIMETERS		
	MIN.	NOM.	MAX.	
Α	0.56	0.58	0.60	
A1	0	0.02	0.10	
b	0.15	0.22	0.30	
С	0.10	0.14	0.18	
D	1.50	1.60	1.70	
E	1.50	1.60	1.70	
E1	1.15	1.20	1.25	
е	0.45	0.50	0.55	
e1	0.95	1.00	1.05	
L	0.25	0.35	0.50	
L1	0.10	0.20	0.30	
C14-0439-Rev. C, 11-Aug-14 DWG: 5880				



RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

APPLICATION NOTE



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000

www.s-manuals.com